Supporting information

Theoretical study on pseudo Mott phase transition of vanadium dioxide

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Table S-1 Comparison	n of stability of spin-po	olarized and spin-unpolarized	zed R and M ₁ phases.

E(eV)	spin-polarization (R)	spin-polarization (M_1)	spin-unpolarization (R)	spin-unpolarization (M_1)
<i>U</i> =2	-151.49	-151.33	-150.72	-150.93
<i>U</i> =0	-144.52	-144.62	-142.59	-143.21

Potential energy surface with linear interpolation



Figure S-1 Potential energy surface of cell shear from M₁ to R phase.



Figure S-2 Free energies and vibrational entropies of several structures at 300 and 400 K along the path A, B and

Evolution of electronic and geometrical structure



Figure S-3 Variation of V-V distances. Red spheres represent oxygen atoms while the others represent

vanadium atoms.



Figure S-4 Schematic diagram of electron orbitals for Peierls transition and Mott transition.



From hole to electron carriers

Figure S-5 Theoretical conductivity (a) and carrier concentrations (b) along the path C.